One Watt High Current Transistors

NPN Silicon

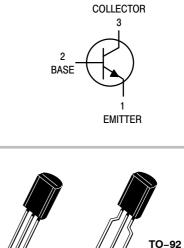
Features

• Pb-Free Packages are Available*



ON Semiconductor®

http://onsemi.com





STRAIGHT LEAD BULK PACK

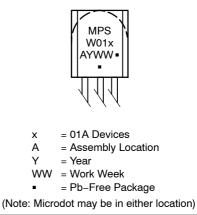
MARKING DIAGRAM

2

3

BENT LEAD

TAPE & REEL AMMO PACK



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS Symbol Value Rating Collector - Emitter Voltage V_{CEO} MPSW01 30 MPSW01A 40 V_{CBO} Collector - Base Voltage MPSW01 40 MPSW01A 50 Emitter-Base Voltage VEBO 5.0 Collector Current - Continuous 1000 I_C Total Device Dissipation @ T_A = 25°C P_D 1.0 Derate above 25°C mW/°C 8.0 Total Device Dissipation @ T_C = 25°C P_D 2.5

THERMAL CHARACTERISTICS

Operating and Storage Junction

Derate above 25°C

Temperature Range

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Unit

Vdc

Vdc

Vdc

mAdc w

w

mW/°C

°C

20

-55 to +150

T_J, T_{stg}

MPSW01, MPSW01A

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

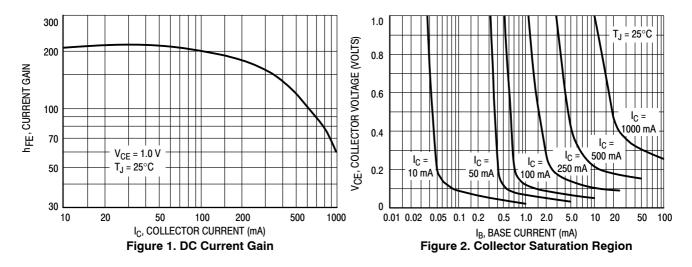
Characteristic			Min	Max	Unit
OFF CHARACTERISTICS		-		•	
Collector – Emitter Breakdown Voltage (Note 1) (I_C = 10 mAdc, I_B = 0)	MPSW01 MPSW01A	V _{(BR)CEO}	30 40		Vdc
Collector – Base Breakdown Voltage (I _C = 100 μ Adc, I _E = 0)	MPSW01 MPSW01A	V _{(BR)CBO}	40 50		Vdc
Emitter – Base Breakdown Voltage (I _E = 100 μ Adc, I _C = 0)		V _{(BR)EBO}	5.0	-	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$	MPSW01 MPSW01A	I _{CBO}	-	0.1 0.1	μAdc
Emitter Cutoff Current (V _{EB} = 3.0 Vdc, I _C = 0)		I _{EBO}	-	0.1	μAdc
ON CHARACTERISTICS (Note 1)					•
		h _{FE}	55 60 50		-
Collector – Emitter Saturation Voltage (I_c = 1000 mAdc, I_B = 100 mAdc)		V _{CE(sat)}	-	0.5	Vdc
Base-Emitter On Voltage (I _C = 1000 mAdc, V _{CE} = 1.0 Vdc)		V _{BE(on)}	-	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain — Bandwidth Product (I _C = 50 mAdc, V _{CE} = 10 Vdc, f = 20 MHz)		f _T	50	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	-	20	pF
Pulse Test: Pulse Width $< 300 \mu s$ Duty Cycle $< 2.0\%$				•	

1. Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

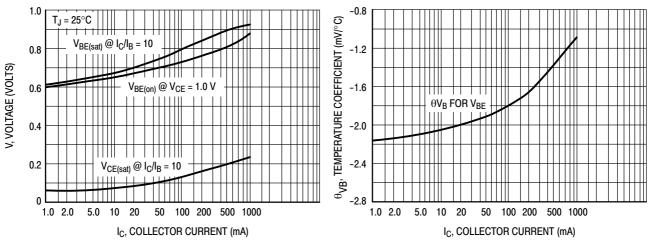
ORDERING INFORMATION

Device	Package	Shipping [†]
MPSW01	TO-92	5000 Units / Bulk
MPSW01G	TO-92 (Pb-Free)	5000 Units / Bulk
MPSW01AG	TO-92 (Pb-Free)	5000 Units / Bulk
MPSW01ARLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSW01ARLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



MPSW01, MPSW01A







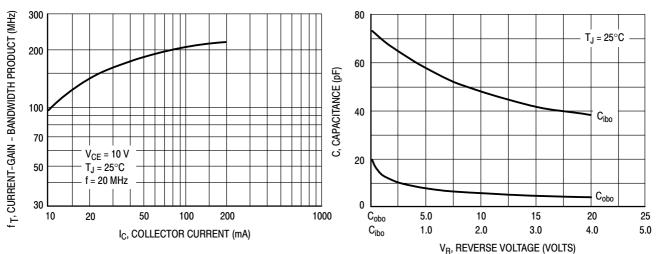


Figure 5. Current Gain — Bandwidth Product

Figure 6. Capacitance

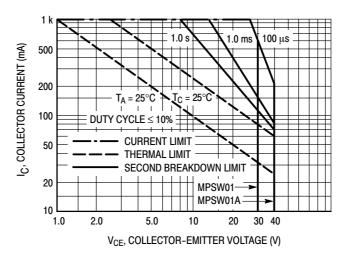
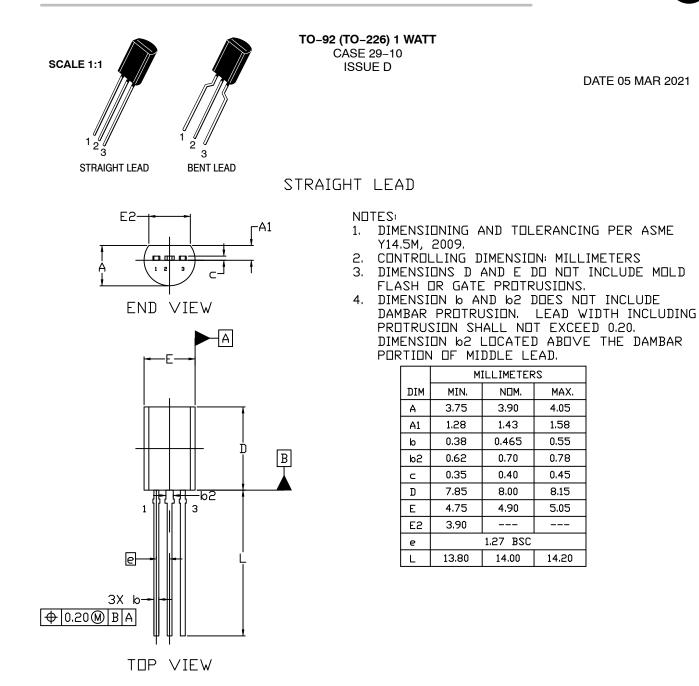


Figure 7. Active Region — Safe Operating Area

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





STYLES AND MARKING ON PAGE 3

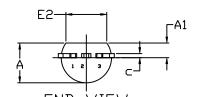
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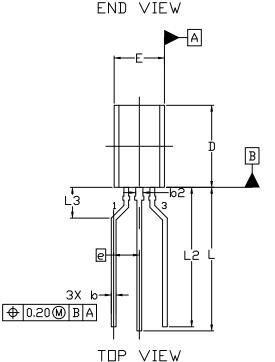


TO-92 (TO-226) 1 WATT CASE 29-10 ISSUE D

DATE 05 MAR 2021

FORMED LEAD





NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS,
- 4. DIMENSION ७ AND ७2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 0.20. DIMENSION ७2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
Α	3.75	3.90	4.05	
A1	1.28	1.43	1.58	
σ	0.38	0.465	0.55	
b2	0.62	0.70	0.78	
с	0.35	0.40	0.45	
D	7.85	8.00	8.15	
Е	4.75	4.90	5.05	
E2	3.90			
e	2.50 BSC			
L	13.80	14.00	14.20	
L2	13.20	13.60	14.00	
L3	3.00 REF			

STYLES AND MARKING ON PAGE 3

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DATE 05 MAR 2021

	EMITTER BASE COLLECTOR
	GATE SOURCE & SUBSTRATE DRAIN
2.	ANODE CATHODE & ANODE CATHODE
2.	ANODE GATE CATHODE
2.	COLLECTOR EMITTER BASE

STYLE 2: PIN 1. BASE 2. EMITTER 3. COLLECTOR STYLE 7: PIN 1. SOURCE 2. DRAIN 3. GATE STYLE 12: PIN 1. MAIN TERMINAL 1 2. GATE 3. MAIN TERMINAL 2 STYLE 17: PIN 1. COLLECTOR 2. BASE 3. EMITTER STYLE 22: PIN 1. SOURCE 2. GATE 3. DRAIN STYLE 27: PIN 1. MT 2. SUBSTRATE 3. MT STYLE 32 PIN 1. BASE 2. COLLECTOR 3. EMITTER

style Pin	1. 2.	ANODE ANODE CATHODE
Style Pin	1. 2.	DRAIN GATE SOURCE & SUBSTRATE
style Pin	1. 2.	ANODE 1 GATE CATHODE 2
style Pin	1. 2.	ANODE CATHODE NOT CONNECTED
style Pin	1. 2.	GATE SOURCE DRAIN
style Pin	1. 2.	CATHODE ANODE GATE
style Pin	1. 2.	RETURN INPUT OUTPUT

STYLE 4: PIN 1. CATHODE STYLE 5: 2. CATHODE 3. ANODE STYLE 9: PIN 1. BASE 1 2. EMITTER 3. BASE 2 STYLE 14: PIN 1. EMITTER 2. COLLECTOR 3. BASE STYLE 19: PIN 1. GATE 2. ANODE 3. CATHODE STYLE 24: PIN 1. EMITTER 2. COLLECTOR/ANODE 3. CATHODE STYLE 29: PIN 1. NOT CONNECTED 2. ANODE 3. CATHODE STYLE 34: PIN 1. INPUT

2. GROUND 3. LOGIC

PIN 1. DRAIN 2. SOURCE 3. GATE STYLE 10: PIN 1. CATHODE 2. GATE 3. ANODE STYLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 STYLE 20: PIN 1. NOT CONNECTED 2. CATHODE 3. ANODE STYLE 25: PIN 1. MT 1 2. GATE 3. MT 2 STYLE 30: PIN 1. DRAIN 2. GATE 3. SOURCE STYLE 35: PIN 1. GATE 2. COLLECTOR 3. EMITTER

GENERIC MARKING DIAGRAM*

XXXXX XXXXX ALYW

XXXX = Specific Device Code

- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
 - = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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